

CMLM0584

**MULTI DISCRETE MODULE™
SURFACE MOUNT SILICON
P-CHANNEL MOSFET AND
LOW V_F SCHOTTKY DIODE**



www.centrasemi.com



SOT-563 CASE

• Device is **Halogen Free** by design

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMLM0584 is a Multi Discrete Module™ consisting of a single P-Channel enhancement-mode MOSFET and a low V_F Schottky diode packaged in a space saving SOT-563 surface mount case. This device is designed for small signal general purpose applications where size and operational efficiency are prime requirements.

MARKING CODE: 58C

FEATURES:

- ESD protection up to 2kV
- Low r_{DS(on)} Transistor (1.5Ω MAX @ V_{GS}=2.5V)
- Low V_F Schottky Diode (0.47V MAX @ 0.5A)

APPLICATIONS:

- DC-DC Converters
- Battery Powered Portable Equipment

MAXIMUM RATINGS - CASE: (T_A=25°C)

Power Dissipation (Note 1)
Power Dissipation (Note 2)
Power Dissipation (Note 3)
Operating and Storage Junction Temperature
Thermal Resistance

SYMBOL		UNITS
P _D	350	mW
P _D	300	mW
P _D	150	mW
T _J , T _{stg}	-65 to +150	°C
θ _{JA}	357	°C/W

MAXIMUM RATINGS - Q1: (T_A=25°C)

Drain-Source Voltage
Gate-Source Voltage
Continuous Drain Current

SYMBOL		UNITS
V _{DS}	30	V
V _{GS}	8.0	V
I _D	450	mA

MAXIMUM RATINGS - D1: (T_A=25°C)

Peak Repetitive Reverse Voltage
Continuous Forward Current
Peak Repetitive Forward Current, tp≤1.0ms
Peak Forward Surge Current, tp=8.0ms

SYMBOL		UNITS
V _{RRM}	40	V
I _F	500	mA
I _{FRM}	3.5	A
I _{FSM}	10	A

ELECTRICAL CHARACTERISTICS - Q1: (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I _{GSSF} , I _{GSSR}	V _{GS} =8.0V, V _{DS} =0			3.0	μA
I _{DSS}	V _{DS} =30V, V _{GS} =0			1.0	μA
BV _{DSS}	V _{GS} =0, I _D =100μA	30			V
V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.5		1.0	V
V _{SD}	V _{GS} =0, I _S =100mA	0.5		1.1	V
r _{DS(ON)}	V _{GS} =4.5V, I _D =430mA			1.1	Ω
r _{DS(ON)}	V _{GS} =2.5V, I _D =200mA			2.0	Ω
r _{DS(ON)}	V _{GS} =1.8V, I _D =100mA			3.3	Ω
g _{FS}	V _{DS} =10V, I _D =100mA	200			mS

Notes: (1) Ceramic or aluminum core PC Board with copper mounting pad area of 4.0mm²
(2) FR-4 Epoxy PC Board with copper mounting pad area of 4.0mm²
(3) FR-4 Epoxy PC Board with copper mounting pad area of 1.4mm²

R4 (1-July 2015)

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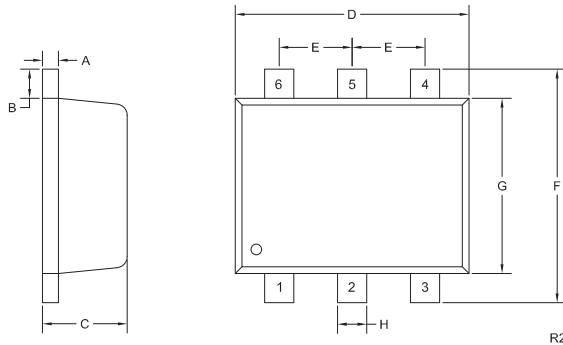
ELECTRICAL CHARACTERISTICS - Q1 - Continued: (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MAX	UNITS
Q _{g(tot)}	V _{DS} =10V, V _{GS} =4.5, I _D =1.0A	0.88	nC
Q _{gs}	V _{DS} =10V, V _{GS} =4.5, I _D =1.0A	0.35	nC
Q _{gd}	V _{DS} =10V, V _{GS} =4.5, I _D =1.0A	0.128	nC
C _{rss}	V _{DS} =25V, V _{GS} =0, f=1.0MHz	10	pF
C _{iss}	V _{DS} =25V, V _{GS} =0, f=1.0MHz	55	pF
C _{oss}	V _{DS} =25V, V _{GS} =0, f=1.0MHz	15	pF

ELECTRICAL CHARACTERISTICS - D1: (T_A=25°C)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I _R	V _R =10V		20	μA
I _R	V _R =30V		100	μA
BV _R	I _R =500μA	40		V
V _F	I _F =100μA		0.13	V
V _F	I _F =1.0mA		0.21	V
V _F	I _F =10mA		0.27	V
V _F	I _F =100mA		0.35	V
V _F	I _F =500mA		0.47	V
C _J	V _R =1.0V, f=1.0MHz		50	pF

SOT-563 CASE - MECHANICAL OUTLINE



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.0027	0.007	0.07	0.18
B	0.008		0.20	
C	0.017	0.024	0.45	0.60
D	0.059	0.067	1.50	1.70
E	0.020		0.50	
F	0.059	0.067	1.50	1.70
G	0.043	0.051	1.10	1.30
H	0.006	0.012	0.15	0.30

SOT-563 (REV: R2)

LEAD CODE:

- 1) Gate Q1
- 2) Source Q1
- 3) Cathode D1
- 4) Anode D1
- 5) Anode D1
- 6) Drain Q1

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R4 (1-July 2015)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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